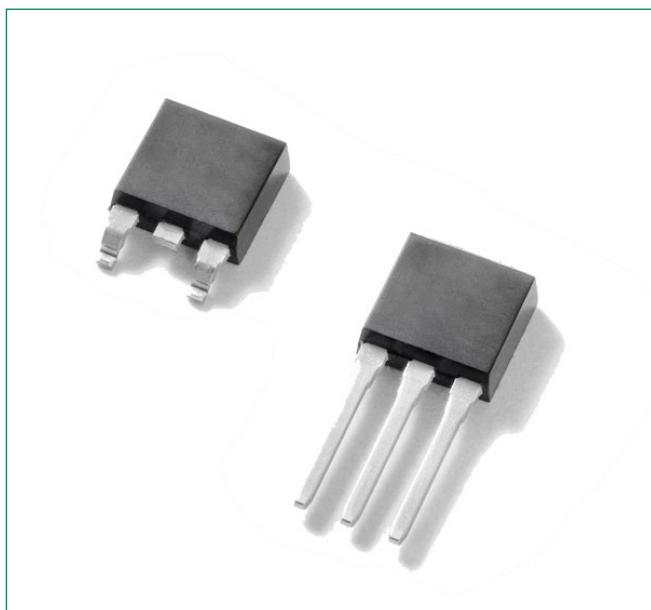




MCR70xA Series



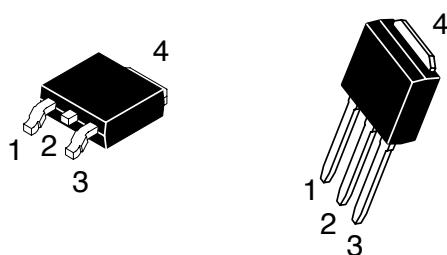
Description

PNPN Components designed for high volume, low cost consumer applications such as temperature, light and speed control; process and remote control; and warning systems where reliability of operation is critical.

Features

- Small Size
- Passivated Die Surface for Reliability and Uniformity
- Low Level Triggering and Holding Characteristics
- Recommend Electrical Replacement for C106
- Surface Mount Package – Case 369C
- To Obtain "DPAK" in Straight Lead Version
(Shipped in Sleeves): Add '1' Suffix to Component Number, i.e., MCR706A1
- UL Recognized compound meeting flammability rating V-0.
- ESD Ratings: Human Body Model, 3B > 8000 V
Machine Model, C > 400 V
- Pb-Free Packages are Available

Pin Out



Functional Diagram



Additional Information

[Datasheet](#)[Resources](#)[Samples](#)

Maximum Ratings ($T_j = 25^\circ\text{C}$ unless otherwise noted)

Rating		Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) ($T_c = -40$ to $+110^\circ\text{C}$, Sine Wave, 50 to 60 Hz, $R_{GK} = 1 \text{ k}\Omega$)	MCR703A MCR706A MCR708A	V_{DRM} V_{RRM}	100 400 600	V
Peak Non-Repetitive Off-State Voltage (180° Conduction Angles; $T_c = 85^\circ\text{C}$)	MCR703A MCR706A MCR708A	V_{DSM}	150 450 650	V
On-State RMS Current (180° Conduction Angles; $T_c = 90^\circ\text{C}$)		$I_{T(RMS)}$	4.0	A
Average On-State Current (180° Conduction Angles)	$T_c = -40$ to $+90^\circ\text{C}$ $T_c = +100^\circ\text{C}$	$I_{T(AV)}$	2.6 1.6	A
Non-Repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, $T_j = 110^\circ\text{C}$) (1/2 Cycle, Sine Wave 1.5 ms, $T_j = 110^\circ\text{C}$)		I_{TSM}	25 35	A
Circuit Fusing Consideration ($t = 8.3$ ms)		I^2t	2.6	A^2sec
Forward Peak Gate Power (Pulse Width $\leq 1.0 \mu\text{sec}$, $T_c = 90^\circ\text{C}$)		I_{GM}	0.5	W
Forward Peak Gate Current (Pulse Width $\leq 1.0 \mu\text{sec}$, $T_c = 90^\circ\text{C}$)		P_{GM}	0.2	A
Forward Average Gate Power ($t = 8.3$ ms, $T_c = 90^\circ\text{C}$)		$P_{G(AV)}$	0.1	W
Operating Junction Temperature Range		T_j	-40 to $+110$	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	-40 to $+150$	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the Component. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect Component reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the Components are exceeded.

Thermal Characteristics*

Rating		Symbol	Value	Unit
Thermal Resistance, Junction-to-Case		R_{ejc}	3.0	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient (Note 2)		R_{eja}	80	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds		T_L	260	$^\circ\text{C}$

2. Case 369C when surface mounted on minimum pad sizes recommended.

Electrical Characteristics - OFF ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak Repetitive Forward or Reverse Blocking Current ($V_{AK} = \text{Rated } V_{DRM}$ or V_{RRM} , $R_{GK} = 1 \text{ k}\Omega$)	$T_J = 25^\circ\text{C}$	I_{DRM}	-	-	10	μA
	$T_J = 110^\circ\text{C}$	I_{RRM}	-	-	200	

Electrical Characteristics - ON ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak Forward "On" Voltage ($I_{TM} = 8.2 \text{ A Peak, Pulse Width = 1 to 2 ms, 2\% Duty Cycle}$)	V_{TM}		-	-	2.2	V
Gate Trigger Current (Continuous dc) (Note 3) ($V_{AK} = 12 \text{ V}; R_L = 24 \Omega$)	$T_J = 25^\circ\text{C}$	I_{GT}	-	25	75	μA
	$T_J = -40^\circ\text{C}$		-	-	300	
Gate Trigger Voltage (Continuous dc) (Note 3) ($V_{AK} = 12 \text{ V}; R_L = 24 \Omega$)	$T_J = 25^\circ\text{C}$	V_{GT}	-	-	0.8	V
	$T_J = -40^\circ\text{C}$		-	-	1.0	
Gate Non-Trigger Voltage (Note 3) ($V_{AK} = 12 \text{ Vdc}; R_L = 100 \Omega, T_c = 110^\circ$)	V_{GD}	0.2	-	-	-	V
Holding Current ($V_{AK} = 12 \text{ Vdc}, R_{GK} = 1 \text{ k}\Omega, T_c = 25^\circ\text{C}$ (Initiating Current = 20 mA) $T_c = -40^\circ\text{C}$)	I_H	-	-	-	5.0	mA
Peak Reverse Gate Blocking Voltage ($I_{GR} = 10 \mu\text{A}$)	V_{RGM}	10	12.5	18	-	
Peak Reverse Gate Blocking Current ($V_{GR} = 10 \text{ V}$)	I_{RGM}	-	-	-	1.2	μA
Total Turn-On Time (Source Voltage = 12 V, $R_S = 6 \text{ k}\Omega$) ($I_{TM} = 8.2 \text{ A}, I_{GT} = 2 \text{ mA, Rated } V_{DRM}$) (Rise Time = 20 ns, Pulse Width = 10 μs)	t_{gt}	-	2.0	-	-	μs

Dynamic Characteristics*

Characteristic	Symbol	Min	Typ	Max	Unit
Critical Rate of Rise of Off-State Voltage ($V_D = \text{Rated } V_{DRM}, R_{GK} = 1 \text{ k}\Omega$, Exponential Waveform, Gate Open, $T_c = 110^\circ\text{C}$)	dv/dt	-	10	-	V/ μs
Repetitive Critical Rate of Rise of On-State Current ($C_f = 60 \text{ Hz}, I_{PK} = 30 \text{ A}, PW = 100 \mu\text{s}, diG/dt = 1 \text{ A}/\mu\text{s}$)	di/dt	-	-	100	A/ μs

3. RGK current not included in measurement.

Thyristors

Surface Mount – 100V -600V > MCR70xA Series

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current

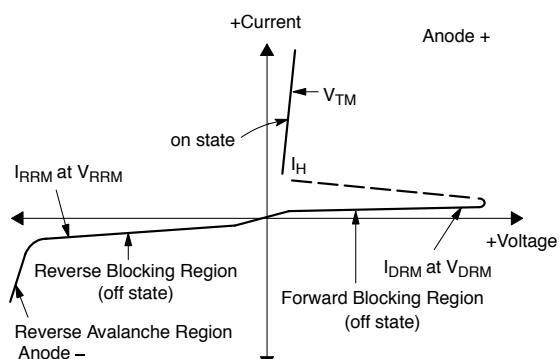


Figure 1. RMS Current Derating

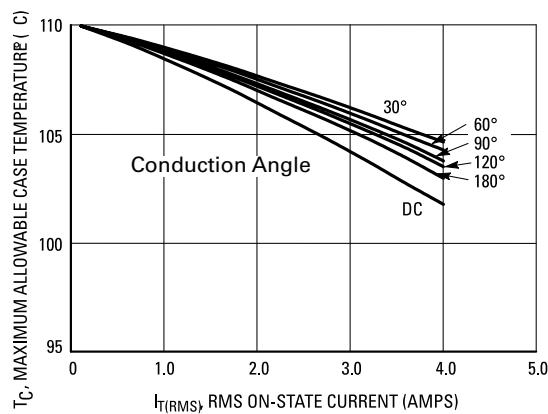


Figure 2. On-State Power Dissipation

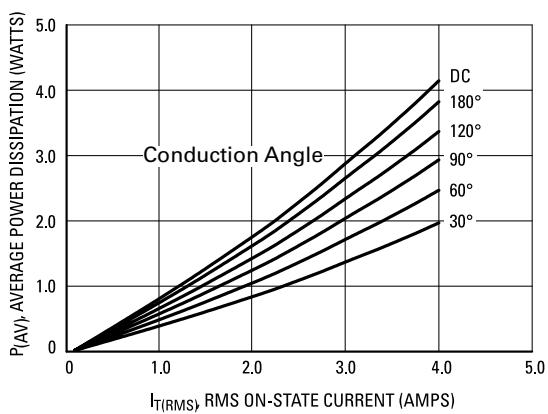


Figure 3. On-State Characteristics

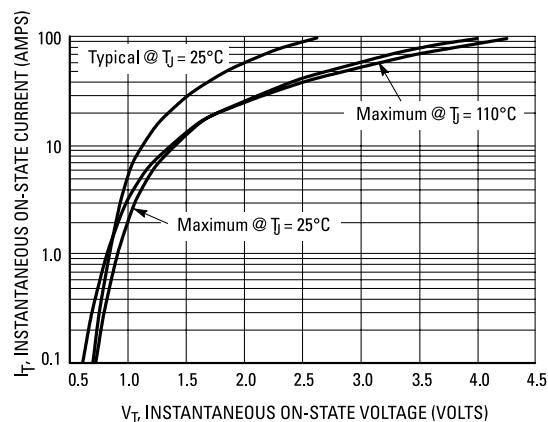
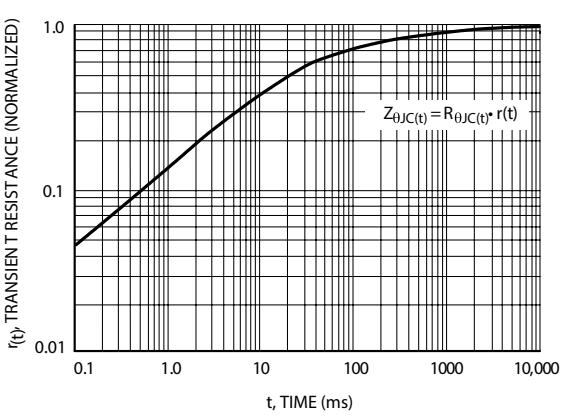


Figure 4. Transient Thermal Response



Thyristors

Surface Mount – 100V -600V > MCR70xA Series

Figure 5. Typical Gate Trigger Current vs Junction Temperature

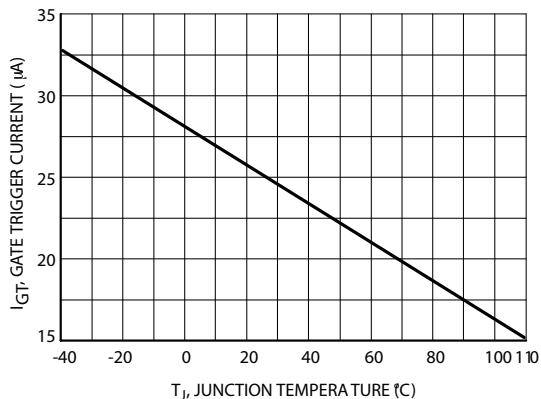


Figure 6. Typical Gate Trigger Voltage vs Junction Temperature

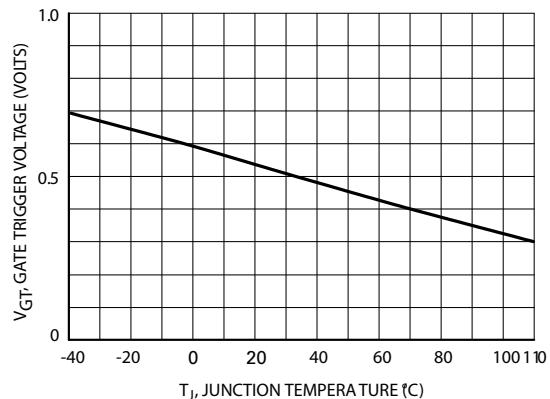


Figure 7. Typical Holding Current vs Junction Temperature

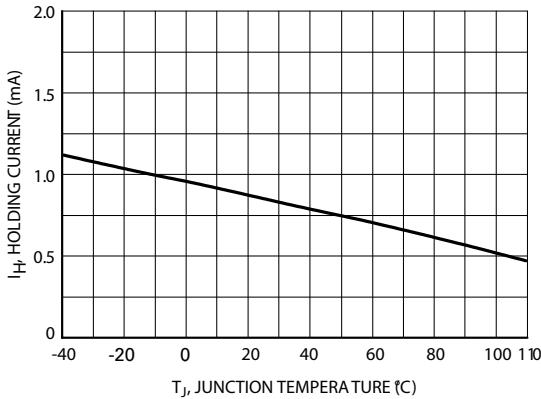
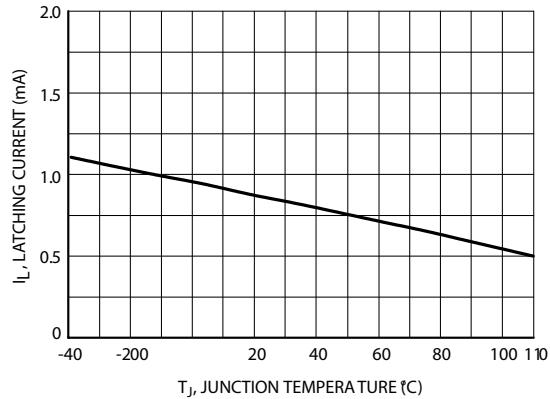


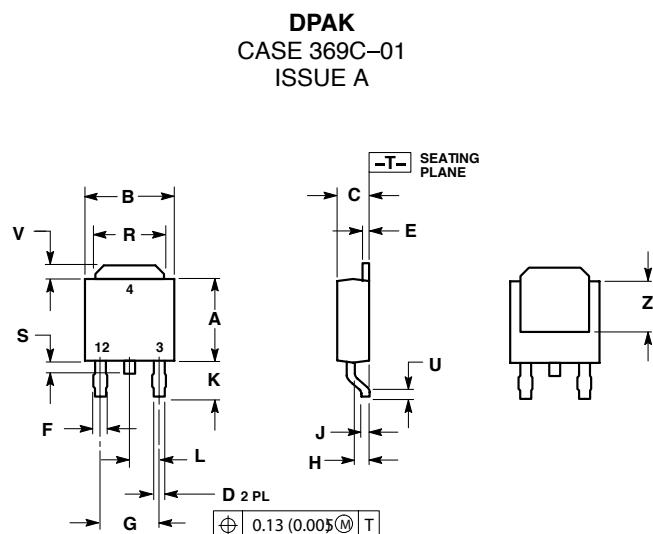
Figure 8. Typical Latching Current vs Junction Temperature



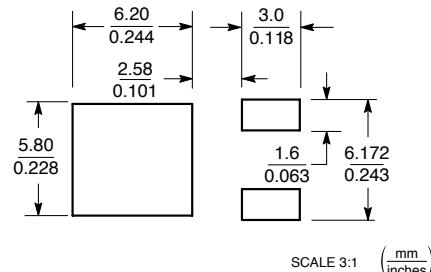
Thyristors

Surface Mount – 100V -600V > MCR70xA Series

Dimensions



Soldering Footprint



Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

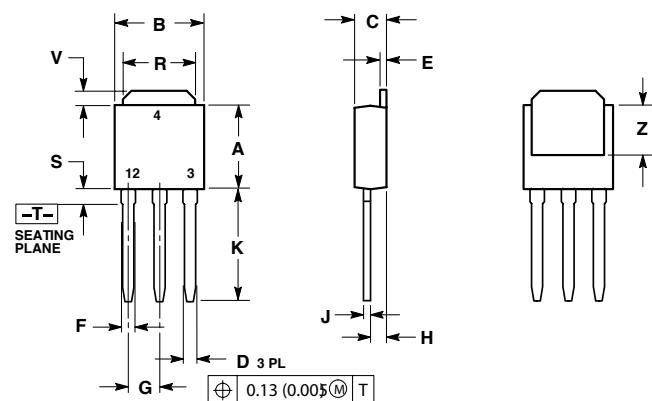
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

Dimensions

DPAK-3
CASE 369D-01
ISSUE B

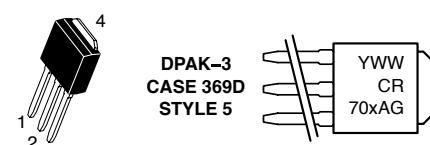


Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: INCH.

Part Marking System



Y = Year
WW = Work Week
70xA = x = 3, 6 or 8
G = Pb-Free Package

Pin Assignment

1	Gate
2	Anode
3	Cathode
4	Anode

Ordering Information

Componant	Package		Shipping
MCR703AT4	DPAK	369C	2500 Tape & Reel
MCR703AT4G		369C (Pb-Free)	
MCR706AT4		369C	
MCR706AT4G		369C (Pb-Free)	
MCR708A		369C	
MCR708AG		369C (Pb-Free)	
MCR708A1	DPAK-3	369D	75 Units/ Rail
MCR708A1G		369D (Pb-Free)	
MCR708AT4		369C	
MCR708AT4G	DPAK	369C (Pb-Free)	2500 Tape & Reel

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ООО "ЛайфЭлектроникс"

"LifeElectronics" LLC

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибуторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибуторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помочь разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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